## NSN 5961-01-030-9857

**Fiig:** A110a0

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View Online at https://aerobasegroup.com/nsn/5961-01-030-9857 **Inclosure Material:** Ceramic or plastic **Overall Length:** 0.785 inches **Terminal Length:** 0.150 inches **Overall Height:** 0.160 inches **Overall Width:** 0.260 inches **Component Name And Quantity:** 5 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 15.0 breakdown voltage, collector-to-emitter, base open all transistor and 20.0 breakdown voltage, collector-to-base, emitter open all transistor and 5.0 breakdown voltage, emitter-to-base, collector open all transistor **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current all transistor and 20.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No